ShinDengen

P26B10SLK

Power MOSFETs
100V, 26A, N-channel

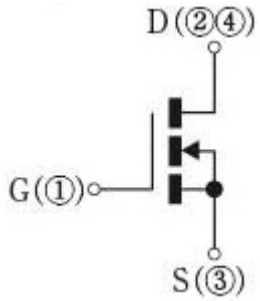
Feature

- N-channel
- SMD
- Low Ron
- 4.5V Gate Drive
- Low Capacitance
- Based on AEC-Q101
- Halogen free
- Pb free terminal
- RoHS:Yes

OUTLINE

Package (House Name): FB
Package (JEDEC Code): TO-252AA

Equivalent circuit



Absolute Maximum Ratings (unless otherwise specified : Tc=25℃)

Item	Symbol	Conditions	Ratings	Unit
Storage temperature	Tstg		-55 to 175	℃
Channel tempertature	Tch		-55 to 175	℃
Drain-source voltage	V_{DSS}		100	V
Gate-source voltage	V_{GSS}		±20	V
Continuous drain current(DC)	I_D		26	A
Continuous drain current(Peak)	I_{DP}	Pulse width 10μs, duty=1/100	78	A
Continuous source current(DC)	Is		26	A
Total power dissipation	P_T	With heatsink※	46	W
Single avalanche current	I_{AS}	Starting Tch=25℃ Tch≦150℃	19	A
Single avalanche energy	E_{AS}	Starting Tch=25℃ Tch≦150℃	40	mJ

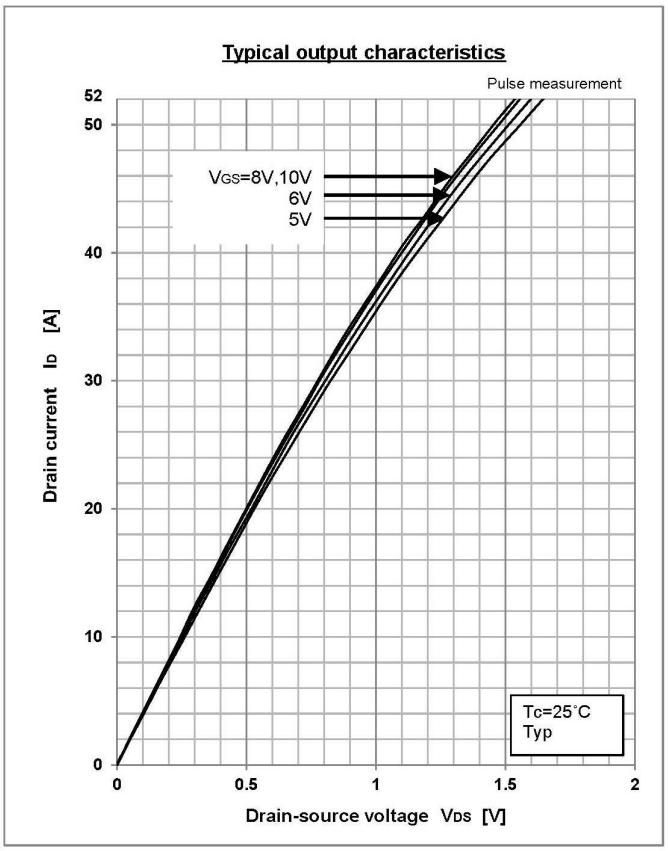
※ ：See the original Specifications

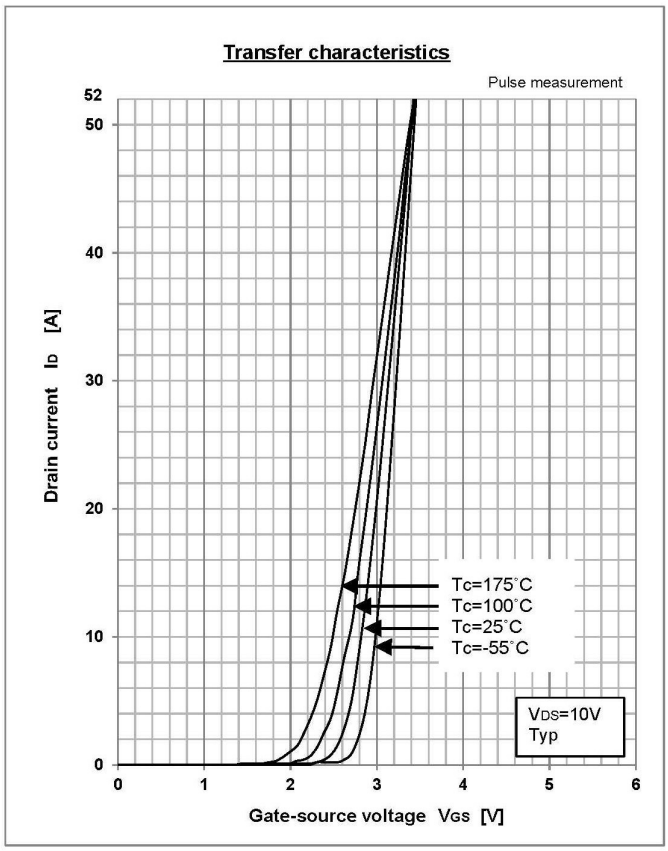
Electrical Characteristics (unless otherwise specified : Tc=25℃)

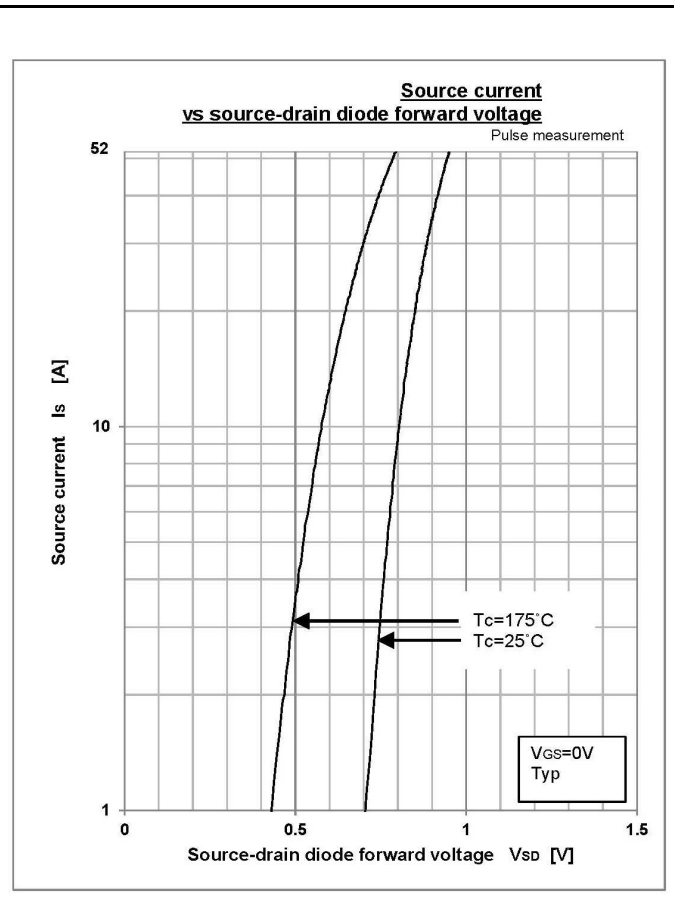
Item	Symbol	Conditions	Ratings			Unit
			MIN	TYP	MAX	
Drain-Source breakdown voltage	$V_{(BR)DSS}$	ID=1mA, VGS=0V	100			V
Zero gate voltage drain current	I_{DSS}	VDS=100V, VGS=0V			1	μA
Gate-source leakage current	I_{GSS}	VGS=±20V, VDS=0V			±0.1	μA
Forward transconductance	g_{fs}	ID=13A, VDS=10V	8	16		S
Static drain-source on-state resistance	$R_{DS(ON)}$	ID=13A, VGS=10V		0.024	0.03	Ω
Static drain-source on-state resistance	$R_{DS(ON)}$	ID=13A, VGS=4.5V		0.026	0.035	Ω
Gate threshold voltage	Vth	ID=1mA, VDS=10V	1.5	2	2.5	V
Source-drain diode forward voltage	V_{SD}	IS=26A, VGS=0V			1.5	V
Thermal resistance	Rth(j-c)	Junction to case, with heatsink ※			3.2	℃/W
Total gate charge	Qg	VDS=80V, VGS=10V, ID=26A		43		nC
Gate to source charge	Qgs	VDS=80V, VGS=10V, ID=26A		9		nC
Gate to drain charge	Qgd	VDS=80V, VGS=10V, ID=26A		12		nC
Input capacitance	Ciss	VDS=25V, VGS=0V, f=1MHz		1975		pF
Reverce transfer capacitnce	Crss	VDS=25V, VGS=0V, f=1MHz		76		pF
Output capacitance	Coss	VDS=25V, VGS=0V, f=1MHz		158		pF
Turn-on delay time	td(on)	ID=13A, RL=3.85Ω, VDS=50V, Rg=0Ω,+VGS=10V, -VGS=0V		6		ns
Rise time	tr	ID=13A, RL=3.85Ω, VDS=50V, Rg=0Ω,+VGS=10V, -VGS=0V		10		ns
Turn-off delay time	td(off)	ID=13A, RL=3.85Ω, VDS=50V, Rg=0Ω,+VGS=10V, -VGS=0V		30		ns
Fall time	tf	ID=13A, RL=3.85Ω, VDS=50V, Rg=0Ω,+VGS=10V, -VGS=0V		17		ns
Diode reverse recovery time	trr	IS=26A, VGS=0V, -di/dt=100A/μs		53		ns
Diode reverse recovery charge	Qrr	IS=26A, VGS=0V, -di/dt=100A/μs		100		nC

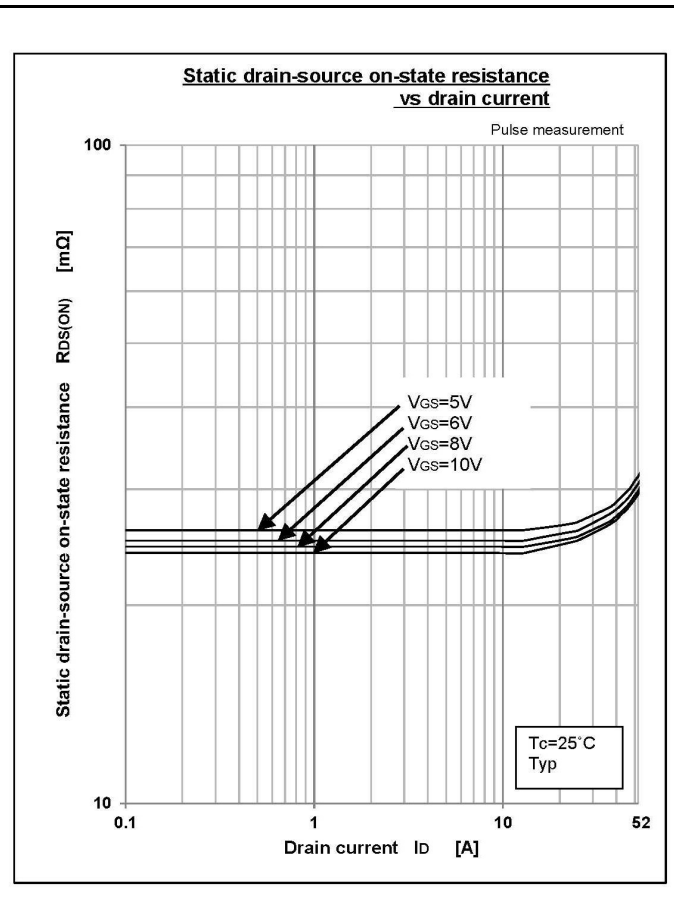
※ ：See the original Specifications

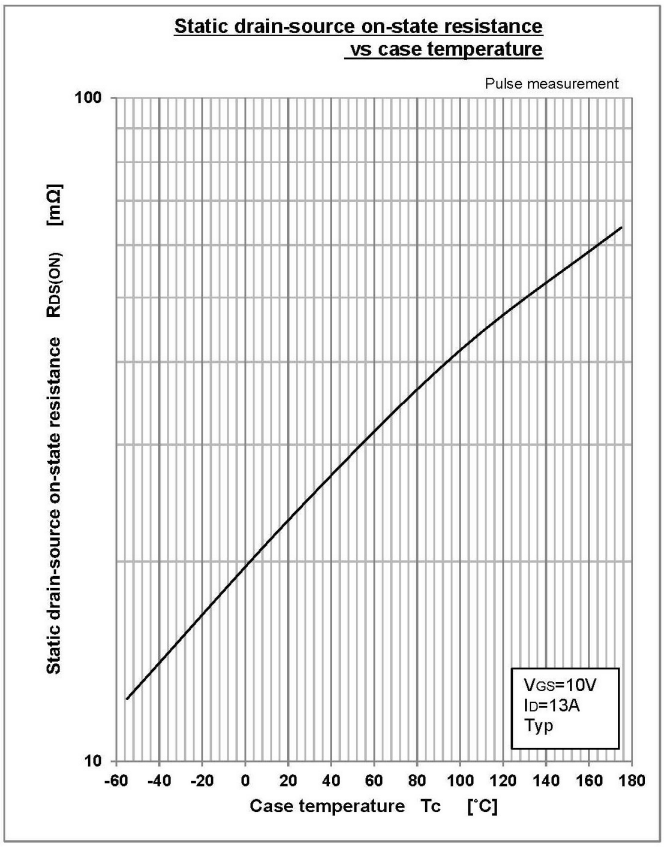
CHARACTERISTIC DIAGRAMS

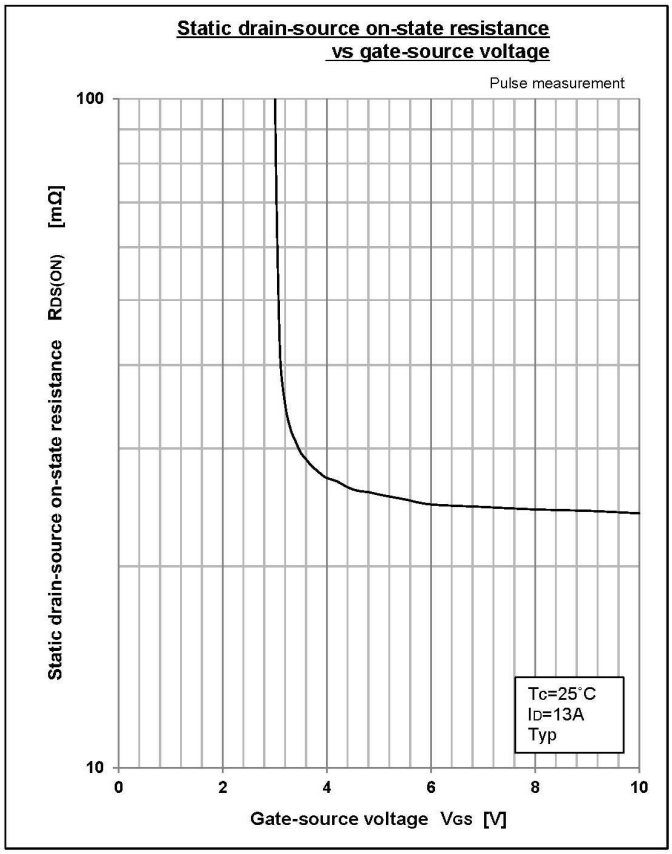


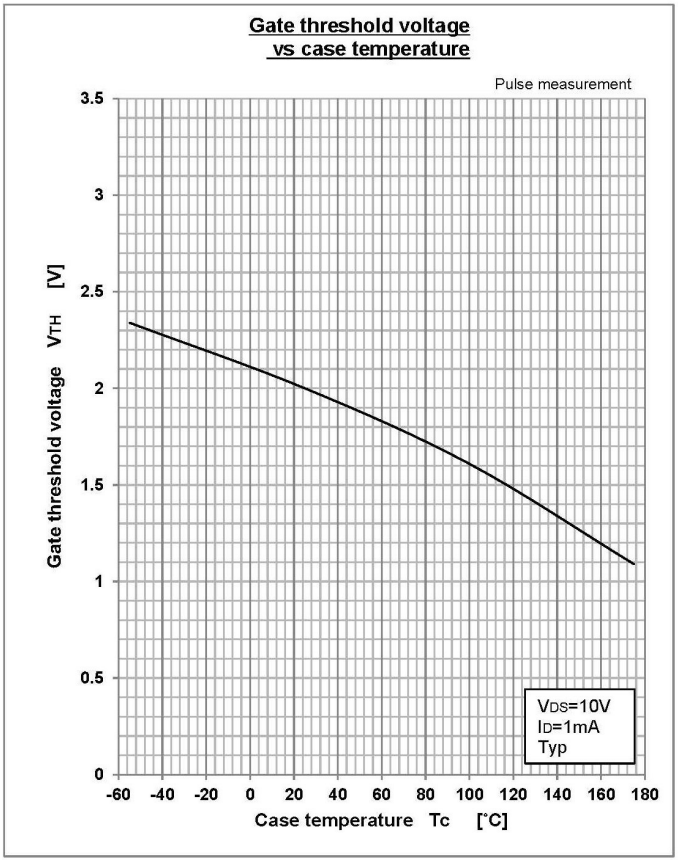


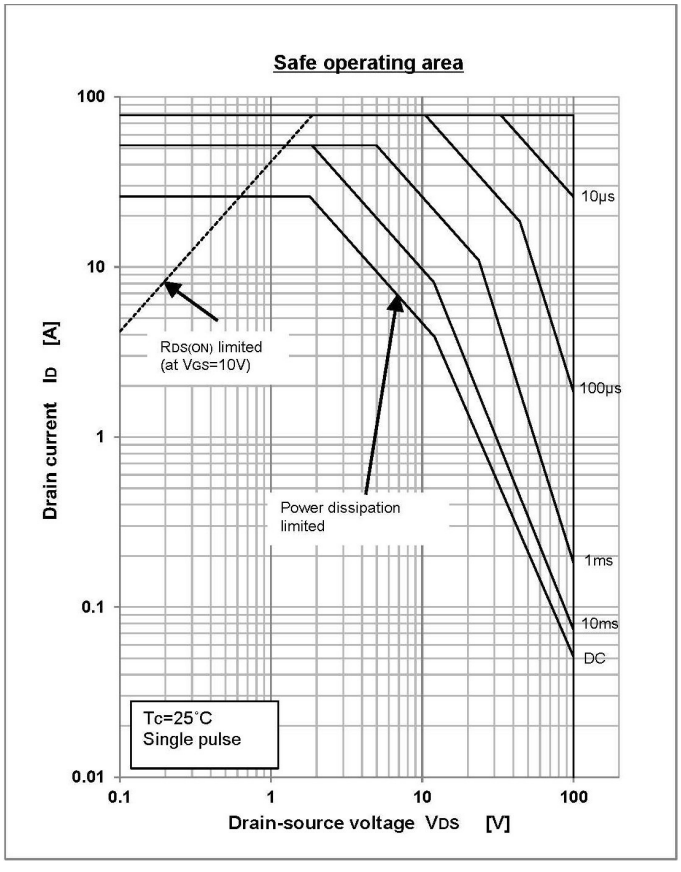


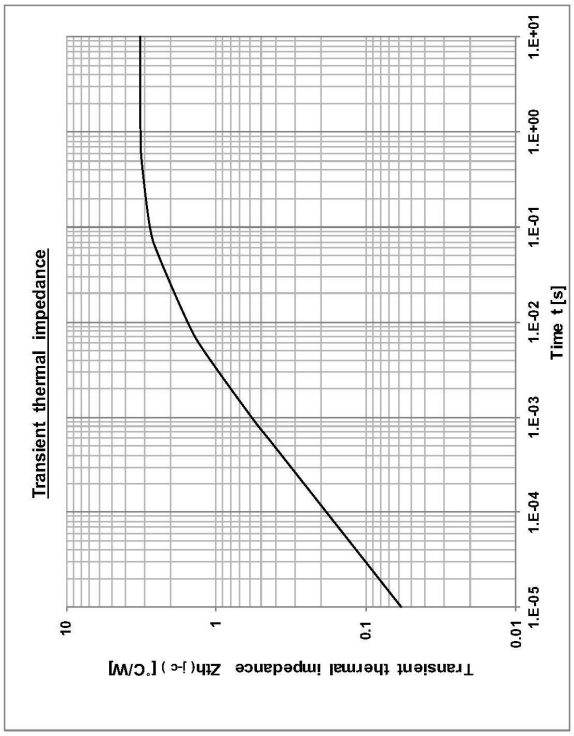



Static drain-source on-state resistance
vs case temperature
Pulse measurement
Static drain-source on-state resistance RDS(ON) [mΩ]
100
10
-60 -40 -20 0 20 40 60 80 100 120 140 160 180
Case temperature Tc [°C]
VGS=10V
ID=13A
Typ

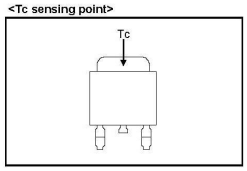

Static drain-source on-state resistance
vs gate-source voltage
Pulse measurement
Static drain-source on-state resistance RDS(ON) [mΩ]
100
10
0 2 4 6 8 10
Gate-source voltage VGS [V]
Tc=25°C
ID=13A
Typ


Gate threshold voltage
vs case temperature
Pulse measurement
Gate threshold voltage VTH [V]
3.5
3
2.5
2
1.5
1
0.5
0
-60 -40 -20 0 20 40 60 80 100 120 140 160 180
Case temperature Tc [°C]
VDS=10V
ID=1mA
Typ


Safe operating area
Drain current ID [A]
100
10
1
0.1
0.01
0.1 1 10 100
Drain-source voltage VDS [V]
10μs
100μs
1ms
10ms
DC
RDS(ON) limited
(at VGS=10V)
Power dissipation
limited
Tc=25°C
Single pulse



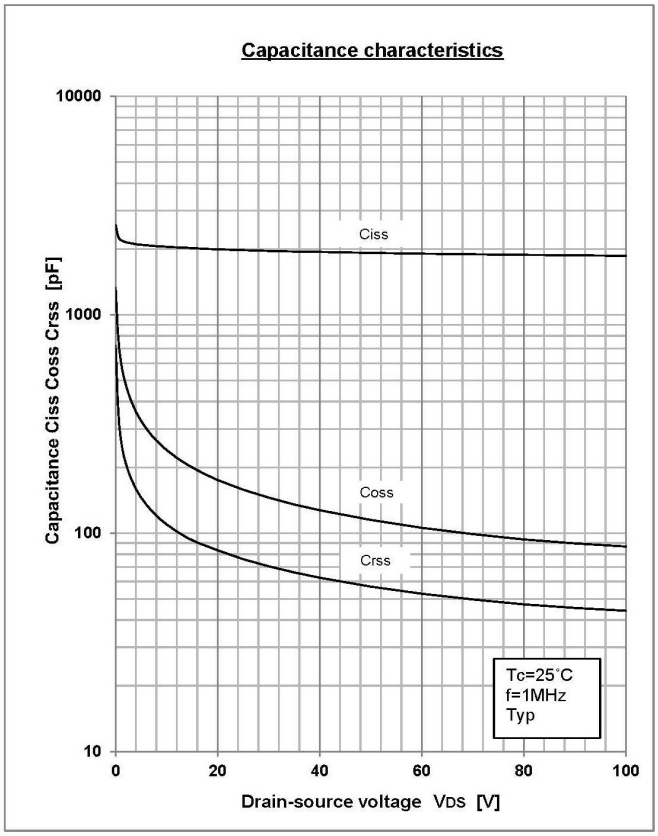
<Tc sensing point>



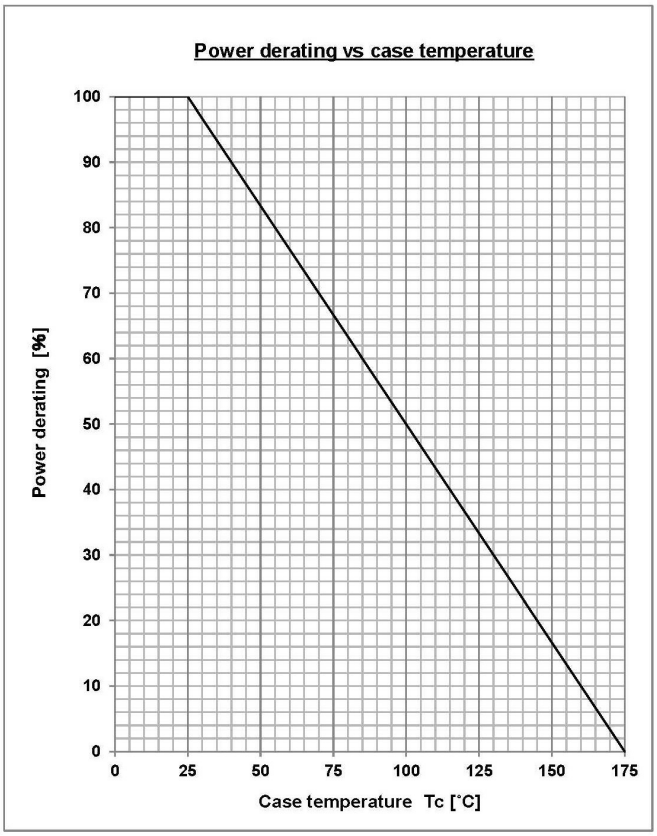
<Substrate detail>

Type	Alumina
Size	1 inch^2
Thickness	0.64 mm
Conductor thickness	20 μm
Pattern area	65 mm^2

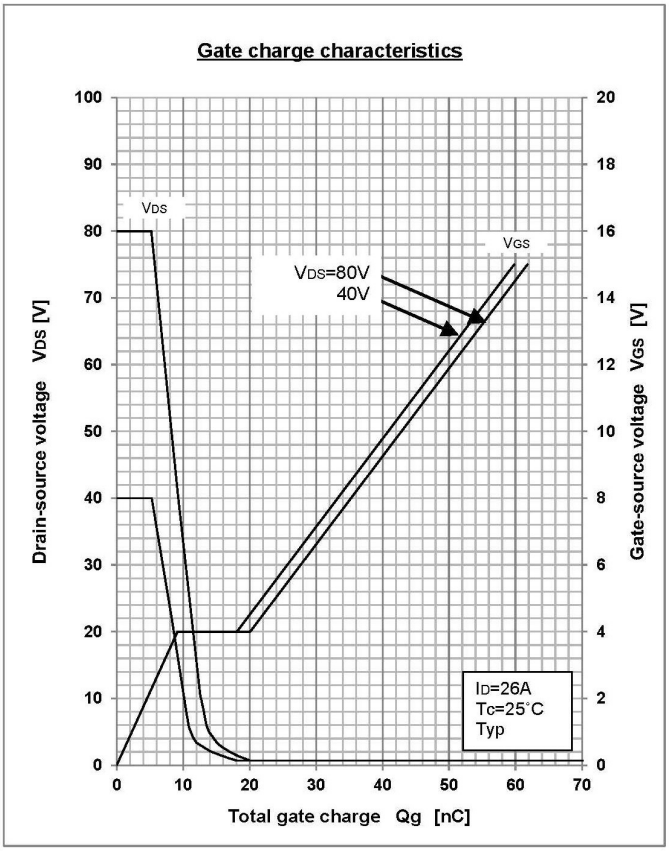
Capacitance characteristics

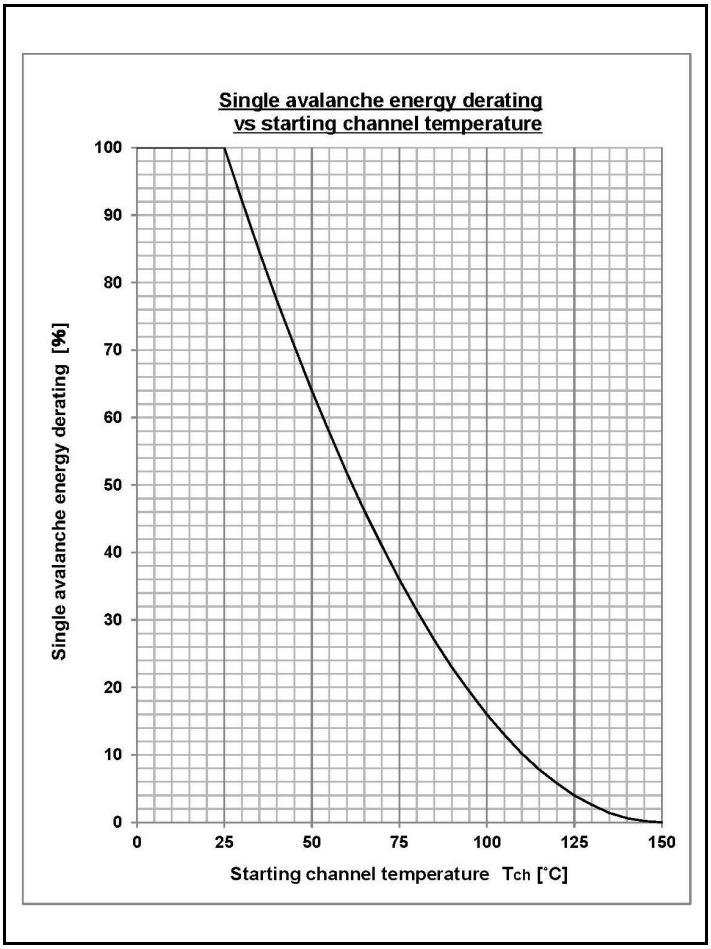


Power derating vs case temperature



Gate charge characteristics



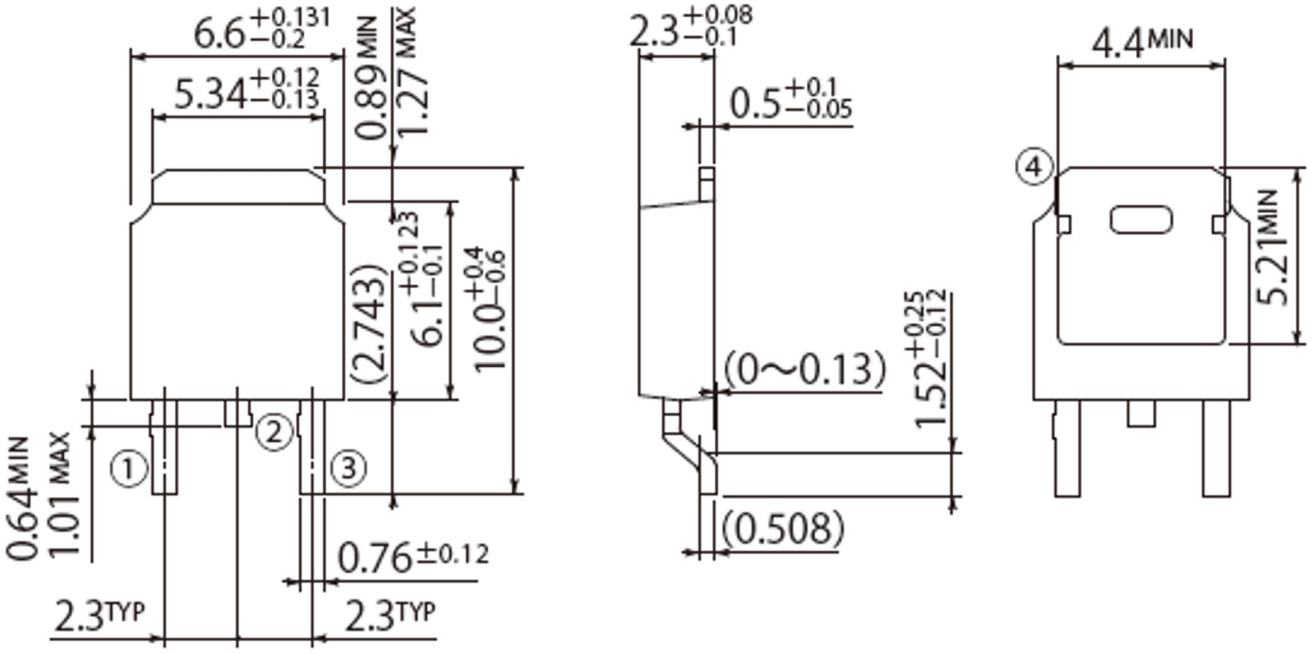

Single avalanche energy derating
vs starting channel temperature
Single avalanche energy derating [%]
100
90
80
70
60
50
40
30
20
10
0
0
25
50
75
100
125
150
Starting channel temperature Tch [°C]

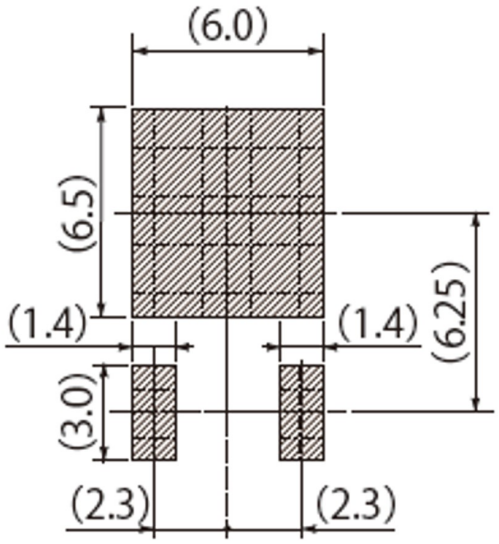
Outline Dimensions

unit:mm

G2

JEDEC Code	TO-252AA
JEITA Code	–
House Name	FB





Referential Soldering Pad

Notes

1. If you wish to use any such product, please be sure to refer to the specifications issued by Shindengen.
2. All products described or contained herein are designed with a quality level intended for use in standard applications requiring an ordinary level of reliability. If these products are to be used in equipment or devices for special or specific applications requiring an extremely high grade of quality or reliability in which failures or malfunctions of products may directly affect human life or health, a local Shindengen office must be contacted in advance to confirm that the intended use of the product is appropriate. Shindengen products are grouped into the following three applications according the quality grade.

   【Standard applications】
   Computers, office automation and other office equipment, communication terminals, test and measurement equipment, audio/visual equipment, amusement equipment, consumer electronics, machine tools, personal electronic equipment, industrial equipment, etc.
   【Special applications】
   Transportation equipment (vehicles, ships, etc.), trunk-line communication equipment, traffic signal control systems, anti-disaster/crime systems, safety equipment, medical equipment, etc.
   【Specific applications】
   Nuclear reactor control systems, aircraft, aerospace equipment, submarine repeaters, life support equipment and systems, etc.
3. Although Shindengen continuously endeavors to enhance the quality and reliability of its products, customers are advised to consider and take safety measures in their design, such as redundancy, fire containment and anti-failure, so that personal injury, fires, or societal damages can be prevented.
4. Please note that all information described or contained herein is subject to change without notice due to product upgrades and other reasons. When buying Shindengen products, please contact the Company's offices or distributors to obtain the latest information.
5. Shindengen shall not bear any responsibility with regards to damages or infringement of any third-party patent rights and other intellectual property rights incurred due to the use of information on this website.
6. The information and materials on this website neither warrant the use of Shindengen's or any third party's patent rights and other intellectual property rights, nor grant license to such rights.
7. In the event that any product described or contained herein falls under the category of strategic products controlled under the Foreign Exchange and Foreign Trade Control Law of Japan, exporting of such products shall require an export license from the Japanese government in accordance with the above law.
8. No reprinting or reproduction of the materials on this website, either in whole or in part, is permitted without proper authorization from Shindengen.